

ON Semiconductor®

FDS9435A

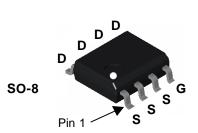
30V P-Channel PowerTrench^{èè} MOSFET

General Description

This PChannel MOSFET is a rugged gate version of ON Semiconductor's advanced PowerTrench process. It has been optimized for power management applications requiring a wide range of gave drive voltage ratings (4.5V - 25V).

Applications

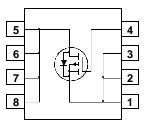
- · Power management
- Load switch
- Battery protection





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• -5.3 A, -30 V R_{DS(ON)} = 50 \text{ m}\Omega @ V_{GS} = -10 \text{ V}
R_{DS(ON)} = 80 \text{ m}\Omega @ V_{GS} = -4.5 \text{ V}
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- · Low gate charge
- Fast switching speed
- + High performance trench technology for extremely low $R_{\text{DS}(\text{ON})}$
- High power and current handling capability

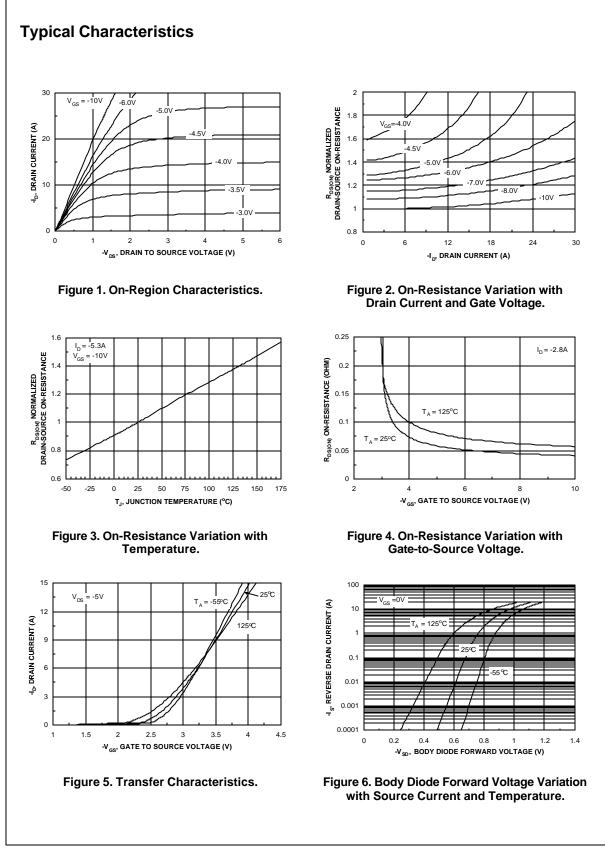


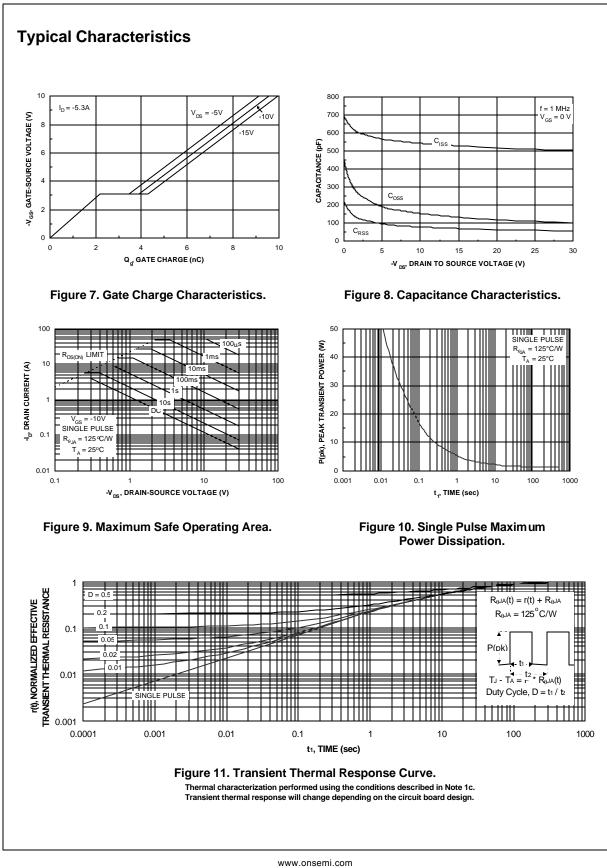
Absolute Maximum Ratings T_A=25°C unless otherwise noted

Symbol	Parameter			Ratings U		
V _{DSS}	Drain-Source	ce Voltage		-30	V	
V _{GSS}	Gate-Sourc	e Voltage		±25	V	
b	Drain Curre	nt – Continuous	(Note 1a)	-5.3	A	
		– Pulsed		-50		
PD	Power Diss	ipation for Single Operation	ON (Note 1a)	2.5	W	
			(Note 1b)	1.2		
			(Note 1c)	1		
T_J, T_{STG}	Operating a	Operating and Storage Junction Temperature Range		-55 to +175	°C	
Therma RejA	I Charac	teristics	Dient (Note 1a)	50	°C/W	
R _{0JA}	Thermal Re	sistance, Junction-to-Aml	bient (Note 1c)	125	°C/W	
R _{0JC}	Thermal Re	sistance, Junction-to-Cas	Se (Note 1)	25	°C/W	
Packag	e Markin	g and Ordering I	nformation			
Device Marking		Device	Reel Size	Tape width	Quantity	
FDS9435A		FDS9435A	13"	12mm	2500 units	

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Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Char	acteristics	1				
BV _{DSS}	Drain–Source Breakdown Voltage	$V_{GS} = 0 V, I_D = -250 \mu A$	-30			V
	Breakdown Voltage Temperature	$I_D = -250 \ \mu$ A, Referenced to 25°C		-23		mV/⁰C
∆Tj bss	Coefficient Zero Gate Voltage Drain Current	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}$			-1	μA
GSSF	Gate–Body Leakage, Forward	$V_{GS} = 25 \text{ V}, V_{DS} = 0 \text{ V}$			100	nA
GSSR	Gate–Body Leakage, Reverse	$V_{GS} = -25 \text{ V} \qquad V_{DS} = 0 \text{ V}$			-100	nA
On Char	acteristics (Note 2)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = -250 \ \mu A$	-1	-1.7	-3	V
<u>ΔVgs(th)</u> ΔTj	Gate Threshold Voltage Temperature Coefficient	$I_D = -250 \ \mu\text{A}$, Referenced to 25°C		4.5		mV/°C
R _{DS(on)}	Static Drain–Source	$V_{GS} = -10 \text{ V}, I_D = -5.3 \text{ A}$		42	50	mΩ
	On–Resistance	$V_{GS} = -4.5 V, I_D = -4 A$		65 57	80 77	
	On Otata Duain Ormant	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -5.3 \text{ A}, \text{ T}_{J} = 125^{\circ}\text{C}$	05	57	11	٨
D(on)	On–State Drain Current Forward Transconductance	$V_{GS} = -10 \text{ V}, V_{DS} = -5 \text{ V}$	-25	10		A S
9 _{FS}		$V_{DS} = -5 V$, $I_D = -5.3 A$		10		3
	Characteristics					
Ciss	Input Capacitance	$V_{DS} = -15 \text{ V}, V_{GS} = 0 \text{ V},$		528		pF
Coss	Output Capacitance	f = 1.0 MHz		132		pF
Crss	Reverse Transfer Capacitance			70		pF
	g Characteristics (Note 2)		1	_		
d(on)	Turn–On Delay Time	$V_{DD} = -15 V$, $I_D = -1 A$, $V_{GS} = -10 V$, $R_{GEN} = 6 \Omega$		7	14	ns
tr	Turn–On Rise Time	$V_{\rm GS} = -10$ V, $N_{\rm GEN} = 0.22$		13	24	ns
t _{d(off)}	Turn-Off Delay Time	4		14	25	ns
t _f	Turn–Off Fall Time	$V_{DS} = -15 V$, $I_D = -4 A$, $V_{GS} = -10 V$		9	17	ns
	Total Gate Charge			10 2.2	14	nC
Q _{gs}	Gate–Source Charge Gate–Drain Charge			2.2		nC nC
Q _{gd}				2		nc
	purce Diode Characteristics			[0.4	•
s	Maximum Continuous Drain–Source Drain–Source Diode Forward	Diode Forward Current			-2.1	A
V _{SD}	Voltage	$V_{GS} = 0 V$, $I_S = -2.1 A$ (Note 2)		-0.8	-1.2	V
	of the junction-to-case and case-to-ambient thermal in R _{eJC} is guaranteed by design while R _{eCA} is determine a) 50°C/W when mounted on a 1in ² pad of 2 oz copper				hen mounte	





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